64Mb (1M×4Bank×16) Synchronous DRAM

Features

- Fully Synchronous to Positive Clock Edge
- Single 3.3V ± 0.3 V Power Supply
- LVTTL Compatible with Multiplexed Address
- Programmable Burst Length (B/L) 1, 2, 4, 8 or Full Page
- Programmable CAS Latency (C/L) 2 or 3
- Data Mask (DQM) for Read / Write Masking
- Programmable Wrap Sequence
- Sequential (B/L = 1/2/4/8/full Page)
- Interleave (B/L = 1/2/4/8)
- Burst Read with Single-bit Write Operation
- All Inputs are Sampled at the Rising Edge of the System Clock
- Auto Refresh and Self Refresh
- 4,096 Refresh Cycles / 64ms (15.625us)

Description

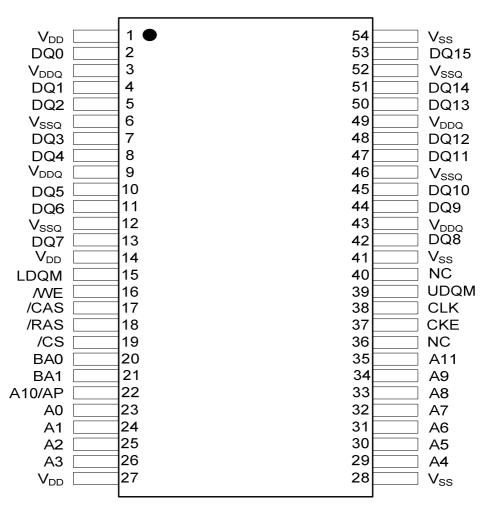
The EM484M1644VTC is Synchronous Dynamic Random Access Memory (SDRAM) organized as 1Meg words x 4 banks by 16 bits. All inputs and outputs are synchronized with the positive edge of the clock.

The 64Mb SDRAM uses synchronized pipelined architecture to achieve high speed data transfer rates and is designed to operate at 3.3V low power memory system. It also provides auto refresh with power saving / down mode. All inputs and outputs voltage levels are compatible with LVTTL. Available packages:TSOPII 54P 400mil.

Part No	Organization	Max. Freq	Package	Grade	Pb
EM484M1644VTC-7F	4M X 16	143MHz @CL3	54pin TSOP(II)	Commercial	Free
EM484M1644VTC-6F	4M X 16	166MHz @CL3	54pin TSOP(II)	Commercial	Free
EM484M1644VTC-7FE	4M X 16	143MHz @CL3	54pin TSOP(II)	Extended	Free
EM484M1644VTC-6FE	4M X 16	166MHz @CL3	54pin TSOP(II)	Extended	Free

Ordering Information

Pin Assignment



54pin TSOP-II / (400mil × 875mil) / (0.8mm Pin pitch)

Pin Description (Simplified)

Pin	Name	Function
38	CLK	(System Clock) Master clock input (Active on the positive rising edge)
19	/CS	(Chip Select) Selects chip when active
37	CKE	(Clock Enable) Activates the CLK when "H" and deactivates when "L". CKE should be enabled at least one cycle prior to new command. Disable input buffers for power down in standby.
23~26, 22, 29~35	A0~A11	 (Address) Row address (A0 to A11) is determined by A0 to A11 level at the bank active command cycle CLK rising edge. CA (CA0 to CA7) is determined by A0 to A7 level at the read or write command cycle CLK rising edge. And this column address becomes burst access start address. A10 defines the pre-charge mode. When A10= High at the pre-charge command cycle, all banks are pre-charged. But when A10= Low at the pre-charge command cycle, only the bank that is selected by BA0/BA1 is pre-charged.
20, 21	BA0, BA1	(Bank Address) Selects which bank is to be active.
18	/RAS	(Row Address Strobe) Latches Row Addresses on the positive rising edge of the CLK with /RAS "L". Enables row access & pre-charge.
17	/CAS	(Column Address Strobe) Latches Column Addresses on the positive rising edge of the CLK with /CAS low. Enables column access.
16	/WE	(Write Enable) Latches Column Addresses on the positive rising edge of the CLK with /CAS low. Enables column access.
39/15	UDQM/LDQM	(Data Input/Output Mask) DQM controls I/O buffers.
2, 4, 5, 7, 8, 10, 11, 13, 42, 44, 45, 47, 48, 50, 51, 53	DQ0~DQ15	(Data Input/Output) DQ pins have the same function as I/O pins on a conventional DRAM.
1,14,27/ 28,41,54	V_{DD}/V_{SS}	(Power Supply/Ground) V_{DD} and V_{SS} are power supply pins for internal circuits.
3, 9, 43, 49/ 6, 12, 46, 52	V_{DDQ}/V_{SSQ}	(Power Supply/Ground) V_{DDQ} and V_{SSQ} are power supply pins for the output buffers.
36,40	NC	(No Connection) This pin is recommended to be left No Connection on the device.

Absolute Maximum Rating

Symbol	Item	Rat	Units		
V _{IN} , V _{OUT}	Input, Output Voltage	-0.3 ~	-0.3 ~ +4.6		
V_{DD}, V_{DDQ}	Power Supply Voltage	-0.3 ~	-0.3 ~ +4.6		
T _{OP}	Operating Temperature Range	Commercial Extended	0 ~ +70 -25 ~ +85	°C	
T _{STG}	Storage Temperature Range		-55 ~ +150		
P _D	Power Dissipation	1		W	
I _{os}	Short Circuit Current	5	0	mA	

Note: Caution Exposing the device to stress above those listed in Absolute Maximum Ratings could cause permanent damage. The device is not meant to be operated under conditions outside the limits described in the operational section of this specification. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

Capacitance (V_{CC}=3.3V, f=1MHz, T_A=25°C)

Symbol	Parameter	Min.	Тур.	Max.	Units
C _{CLK}	Clock Capacitance	2.5		4.0	pF
Cı	Input Capacitance for CLK, CKE, Address, /CS, /RAS, /CAS, /WE, DQML, DQMU	2.5		5.0	pF
Co	Input/Output Capacitance	4.0		6.5	pF

Recommended DC Operating Conditions (T_A =-0°C ~+70°C)

Symbol	Parameter	Min.	Тур.	Max.	Units
V _{DD}	Power Supply Voltage	3.0	3.3	3.6	V
V _{DDQ}	Power Supply Voltage (for I/O Buffer)	3.0	3.3	3.6	V
V _{IH}	Input Logic High Voltage	2.0		V _{DD} +0.3	V
V _{IL}	Input Logic Low Voltage	-0.3		0.8	V

Note: * All voltages referred to V_{SS}.

* V_{IH} (max.) = 5.6V for pulse width 3ns

* V_{IL} (min.) = -2.0V for pulse width 3ns

Recommended DC Operating Conditions

$(V_{DD}=3.3V\pm0.3V, T_{A}=0^{\circ}C \sim 70^{\circ}C)$

Symbol	Parameter	Test Conditions	Max.	Units
I _{CC1}	Operating Current (Note 1)	Burst length=1, t _{RC} ≥t _{RC} (min.), I _{OL} =0mA, One bank active	90	mA
I _{CC2P}	Precharge Standby Current in	CKE≤V _{IL} (max.), t _{CK} =15ns	2	mA
I _{CC2PS}	Power Down Mode	CKE≤V _{IL} (max.), t _{CK} =∞	1	mA
I _{CC2N}	Precharge Standby Current in Non-power Down Mode	CKE≥V _{IL} (min.), t _{CK} =15ns, /CS≥V _{IH} (min.) Input signals are changed one time during 30ns	20	mA
I _{CC2NS}		CKE≥V _{IL} (min.), t _{CK} =∞ , Input signals are stable	20	mA
I _{CC3P}	Active Standby Current in	CKE≤V _{IL} (max.), t _{CK} =15ns	7	mA
I _{CC3PS}	Power Down Mode	CKE≤V _{IL} (max.), t _{CK} =∞	5	mA
I _{CC3N}	Active Standby Current in Non-power Down Mode	CKE≥V _{IL} (min.), t _{CK} =15ns, /CS≥V _{IH} (min.) Input signals are changed one time during 30ns	30	mA
I _{CC3NS}		CKE≥V _{IL} (min.), t _{CK} =∞ , Input signals are stable	35	mA
I _{CC4}	Operating Current (Burst Mode) ^(Note 2)	t _{CCD} ≥2CLKs, I _{OL} =0mA	120	mA
I _{CC5}	Refresh Current (Note 3)	t _{RC} ≥t _{RC} (min.)	140	mA
I _{CC6}	Self Refresh Current	CKE≤0.2V	1 ^(Note 4)	mA

*All voltages referenced to V_{SS} .

Note 1: I_{CC1} depends on output loading and cycle rates. Specified values are obtained with the output open. Input signals are changed only one time during t_{CK} (min.)

Note 2: I_{CC4} depends on output loading and cycle rates. Specified values are obtained with the output open. Input signals are changed only one time during t_{CK} (min.)

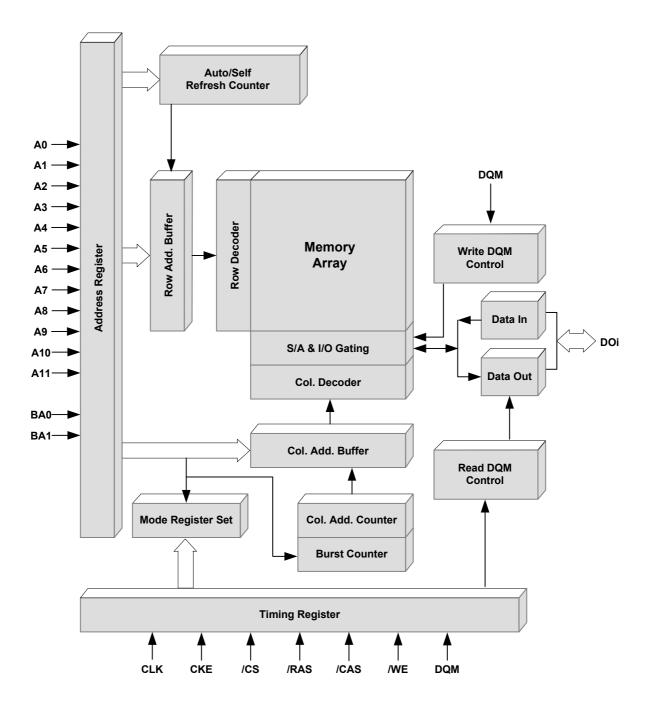
Note 3: Input signals are changed only one time during t_{CK} (min.)

Note 4: Standard power version.

Recommended DC Operating Conditions (Continued)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
IIL	Input Leakage Current	0≤V _I ≤V _{DDQ} , V _{DDQ} =V _{DD} All other pins not under test=0V	-0.5		+0.5	uA
I _{OL}	Output Leakage Current	$0 \le V_O \le V_{DDQ}$, D_{OUT} is disabled	-0.5		+0.5	uA
V _{OH}	High Level Output Voltage	I _O =-4mA	2.4			V
V _{OL}	Low Level Output Voltage	I _O =+4mA			0.4	V

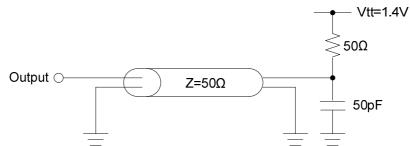
Block Diagram



AC Operating Test Conditions

(V _{DD} =3.3V±0.3V, T _A =0°C ~70	°C)
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Item	Conditions
Output Reference Level	1.4V/1.4V
Output Load	See diagram as below
Input Signal Level	2.4V/0.4V
Transition Time of Input Signals	2ns
Input Reference Level	1.4V



AC Operating Test Characteristics

(V_{DD}=3.3V±0.3V, T_A=0°C ~70°C)

Sumbol	Doromotor		-	6	-	7	Linita
Symbol	Parameter		Min.	Max.	Min.	Max.	Units
+	Clock Cycle Time	CL=3	6		7		20
t _{CK}	Clock Cycle Time	CL=2	7.5		7.5		ns
	Access Time form CLK	CL=3		5.5		6	20
t _{AC}	Access Time form CLK	CL=2		6		6	ns
t _{CH}	CLK High Level Width		2.5		3		ns
t _{CL}	CLK Low Level Width		2.5		3		ns
•	Data-out Hold Time	CL=3	2.5				20
t _{OH}		CL=2			2.5		ns
4	Data-out High Impedance	CL=3	2.5	5		6	20
t _{HZ}	Time ^(Note 5)	CL=2				6	ns
t _{LZ}	Data-out Low Impedance Time		0		0		ns
t _{IH}	Input Hold Time		1		1		ns
t _{IS}	Input Setup Time		2		2		ns

* All voltages referenced to V_{SS} .

Note 5: t_{HZ} defines the time at which the output achieve the open circuit condition and is not referenced to output voltage levels.

AC Operating Test Characteristics (Continued)

(V _{DD} =3.3V±0.3V, T _A	_A =0°C ~70°C)
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Symbol	Parameter		-6		-	7	Units
Symbol	Farameter		Min.	Max.	Min.	Max.	Units
t _{RC}	ACTIVE to ACTIVE Comman Period (Note 6)	nd	60		63		ns
t _{RAS}	ACTIVE to PRECHARGE Command Period (Note 6)		42	100k	42	100k	ns
t _{RP}	PRECHARGE to ACTIVE Command Period (Note 6)		18		18		ns
t _{RCD}	ACTIVE to READ/WRITE Delay Time ^(Note 6)		18		18		ns
t _{RRD}	ACTIVE(one) to ACTIVE(another) Command (Note 6)		14		16		ns
t _{CCD}	READ/WRITE Command to READ/WRITE Command		1		1		CLK
t _{DPL}	Date-in to PRECHARGE Command		2		2		CLK
t _{BDL}	Date-in to BURST Stop Com	mand	1		1		CLK
	Data-out to High	CL=3	3		3		0.17
t _{ROH}	Impedance from PRECHARGE Command	CL=2			2		CLK
t _{REF}	Refresh Time (4,096 cycle)			64		64	ms

* All voltages referenced to V_{SS} .

Note 6: These parameters account for the number of clock cycles and depend on the operating frequency of the clock, as follows:

The number of clock cycles = Specified value of timing/clock period (Count Fractions as a whole number)

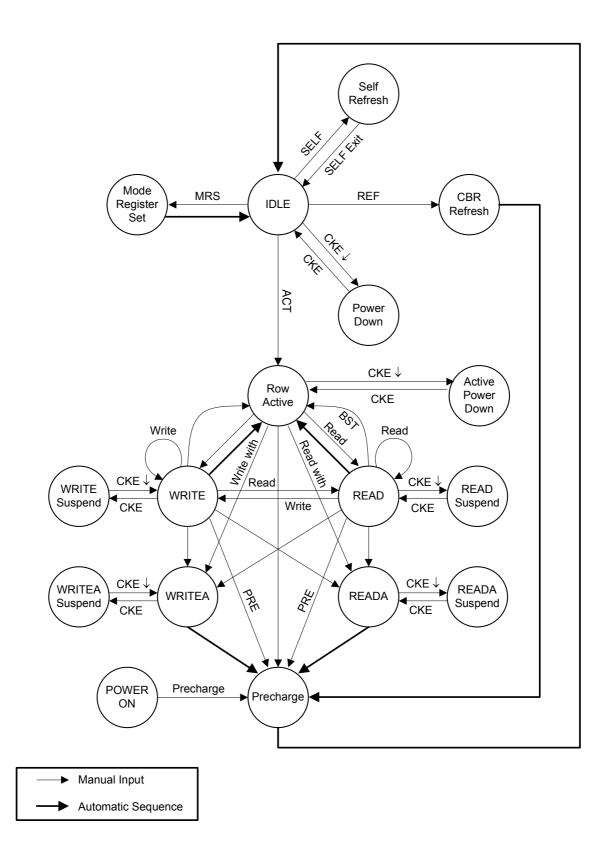
Recommended Power On and Initialization

The following power on and initialization sequence guarantees the device is preconditioned to each user's specific needs. (Like a conventional DRAM) During power on, all V_{DD} and V_{DDQ} pins must be built up simultaneously to the specified voltage when the input signals are held in the "NOP" state. The power on voltage must not exceed V_{DD} +0.3V on any of the input pins or V_{DD} supplies. (CLK signal started at same time)

After power on, an initial pause of 200 µs is required followed by a precharge of all banks using the precharge command.

To prevent data contention on the DQ bus during power on, it is required that the DQM and CKE pins be held high during the initial pause period. Once all banks have been precharged, the Mode Register Set Command must be issued to initialize the Mode Register. A minimum of eight Auto Refresh cycles (CBR) are also required, and these may be done before or after programming the Mode Register.

Simplified State Diagram



Address Input for Mode Register Set

BA1	BA) A11	A10	A9	A8	A7	A6		A5	A4	A3	A2	A		۹0
		0	peration N	Node			(CAS	Latenc	у	BT	Βι	Burst Length		
											Burst	Lengt	th		
									Seque	ntial	Interl	-	A2	A1	A0
									1				0	0	0
									2		2	2	0	0	1
									4		4	1	0	1	0
									8		8	3	0	1	1
									Reser	ved	Rese	erved	1	0	0
									Reser		Rese		1	0	1
									Reser		Rese		1	1	0
									Full Pa	age	Rese	erved	1	1	1
	Burst Type Interleave Sequential										43 1 0				
				CAS	S Latency	/	A6		A5		A4				
					eserved		0		0		0				
					eserved		0		0		1				
					2		0		1		0				
					3		0		1		1				
					eserved		1		0		0				
					eserved		1		0		1				
					eserved		1		1		0				
				Re	eserved		1		1		1]			
E	BA1	BA0	A11	A10	A9	A8	A	47		(Operat	ion Mo	ode		
	0	0	0	0	0	0		0	Normal						
	0	0	0	0	1	0		0	Burst Read with Single-bit Write						

LOTEX Burst Type (A3)

Burst Length	A2	A1	A0	Sequential Addressing	Interleave Addressing
0	Х	Х	0	0 1	0 1
2	Х	Х	0	10	10
	Х	0	0	0123	0123
4	Х	0	1	1230	1 0 3 2
4	Х	1	0	2301	2301
	Х	1	1	3012	3210
	0	0	0	0 1 2 3 4 5 6 7	0 1 2 3 4 5 6 7
	0	0	1	12345670	10325476
	0	1	0	23456701	23016745
0	0	1	1	34567012	32107654
8	1	0	0	45670123	45670123
	1	0	1	56701234	54761032
	1	1	0	67012345	67452301
	1	1	1	70123456	76543210
Full Page*	n	n	n	Cn Cn+1 Cn+2	-

* Page length is a function of I/O organization and column addressing ×16 (CA0 ~ CA7): Full page = 256bits

Command	Symbol	CK	E	/CS	/RAS	/CAS	/WE	BA0,	A10	A11,
Command	Symbol	n-1	n	/03	/NAS	/CAS	/ • • ⊏	BA1	AIU	A9~A10
Ignore Command	DESL	Н	Х	Н	Х	Х	Х	Х	Х	Х
No Operation	NOP	Н	Х	L	Н	Н	Н	Х	Х	Х
Burst Stop	BSTH	Н	Х	L	Н	Н	L	Х	Х	Х
Read	READ	Н	Х	L	Н	L	Н	V	L	V
Read with Auto Pre-charge	READA	Н	Х	L	Н	L	Н	V	Н	V
Write	WRIT	Н	Х	L	Н	L	L	V	L	V
Write with Auto Pre-charge	WRITA	Н	Х	L	L	Н	Н	V	Н	V
Bank Activate	ACT	Н	Х	L	L	Н	Н	V	V	V
Pre-charge Select Bank	PRE	Н	Х	L	L	Н	L	V	L	Х
Pre-charge All Banks	PALL	Н	Х	L	L	Н	L	Х	Н	Х
Mode Register Set	MRS	Н	Х	L	L	L	L	L	L	V

1. Command Truth Table

H = High level, L = Low level, X = High or Low level (Don't care), V = Valid data input

2. DQM Truth Table

Command	Symbol	CI	ΚE	/CS	
Command	Symbol	n-1	n	703	
Data Write/Output Enable	ENB	Н	Х	Н	
Data Mask/Output Disable	MASK	Н	Х	L	
Upper Byte Write Enable/Output Enable	BSTH	Н	Х	L	
Read	READ	Н	Х	L	
Read with Auto Pre-charge	READA	Н	Х	L	
Write	WRIT	Н	Х	L	
Write with Auto Pre-charge	WRITA	Н	Х	L	
Bank Activate	ACT	Н	Х	L	
Pre-charge Select Bank	PRE	Н	Х	L	
Pre-charge All Banks	PALL	Н	Х	L	
Mode Register Set	MRS	Н	Х	L	

H = High level, L = Low level, X = High or Low level (Don't care), V = Valid data input

3. CKE Truth Table

ltem	Command	Symbol	CK	E	/CS	/RAS	/CAS	/WE	Addr.
nem	Command	Symbol	n-1	n	/03	/NAS	/CA3	/ / / ⊏	Auur.
Activating	Clock Suspend Mode Entry		Н	L	Х	Х	Х	Х	Х
Any	Clock Suspend Mode		L	L	Х	Х	Х	Х	Х
Clock Suspend	Clock Suspend Mode Exit		L	н	х	Х	Х	Х	Х
Idle	CBR Refresh Command	REF	Н	Н	L	L	L	Н	Х
Idle	Self Refresh Entry	SELF	Н	L	L	L	L	Н	Х
Self Refresh	Self Refresh Exit		L	Н	L	Н	Н	Н	Х
Sell Reflesh			L	Н	Н	Х	Х	Х	Х
Idle	Power Down Entry		Н	L	Х	Х	Х	Х	Х
Power Down	Power Down Exit		L	Н	Х	Х	Х	Х	Х

Remark H = High level, L = Low level, X = High or Low level (Don't care)

4. Opera	tive	Со	тп	nano	d Table ^{(Ne}	ote 7)	
Current State	/CS	/R	/C	/W	Addr.	Command	Action
	Н	Х	Х	Х	Х	DESL	Nop or power down (Note 8)
-	L	Н	н	Х	Х	NOP or BST	Nop or power down (Note 8)
-	L	Н	L	н	BA/CA/A10	READ/READA	ILLEGAL ^(Note 9)
-	L	Н	L	L	BA/CA/A10	WRIT/WRITA	ILLEGAL ^(Note 9)
Idle	L	L	н	н	BA/RA	ACT	Row activating
-	L	L	Н	L	BA, A10	PRE/PALL	Nop
	L	L	L	н	х	REF/SELF	Refresh or self refresh (Note 10)
-	L	L	L	L	Op-Code	MRS	Mode register accessing
	Η	Х	Х	Х	Х	DESL	Nop
	L	Н	Н	Х	Х	NOP or BST	Nop (Note 11)
	L	Н	L	Н	BA/CA/A10	READ/READA	Begin read: Determine AP (Note 11)
Row	L	Н	L	L	BA/CA/A10	WRIT/WRITA	Begin write: Determine AP (Note 11)
Active	L	L	н	н	BA/RA	ACT	ILLEGAL ^(Note 9)
	L	L	Н	L	BA, A10	PRE/PALL	Pre-charge (Note 12)
	L	L	L	Н	Х	REF/SELF	ILLEGAL (Note 10)
	L	L	L	L	Op-Code	MRS	ILLEGAL
	Н	Х	Х	Х	Х	DESL	Continue burst to end \rightarrow Row active
	L	Н	Н	Н	Х	NOP	Continue burst to end \rightarrow Row active
	L	Н	Н	L	Х	BST	Burst stop \rightarrow Row active
	L	н	L	н	BA/CA/A10	READ/READA	Terminate burst, new read: Determine AP ^(Note 13)
Read	L	L	L	L	BA/CA/A10	WRIT/WRITA	Terminate burst, start write: Determine AP ^(Note 13, 14)
-	L	L	н	н	BA/RA	ACT	ILLEGAL (Note 9)
	L	L	н	L	BA, A10	PRE/PALL	Terminate burst, pre-charging (Note 10)
	L	L	L	Н	Х	REF/SELF	ILLEGAL
	L	L	L	L	Op-Code	MRS	ILLEGAL
	Н	х	х	Х	х	DESL	Continue burst to end \rightarrow Write recovering
	L	н	н	н	X	NOP	Continue burst to end \rightarrow Write recovering
-	L	Н	Н	L	Х	BST	Burst stop \rightarrow Row active
	L	н	L	н	BA/CA/A10	READ/READA	Terminate burst, start read: Determine AP 7, 8 ^(Note 13, 14)
Write	L	L	L	L	BA/CA/A10	WRIT/WRITA	Terminate burst, new write: Determine AP 7 ^(Note 13)
-	L	L	н	н	BA/RA	ACT	ILLEGAL ^(Note 9)
	L	L	н	L	BA, A10	PRE/PALL	Terminate burst, pre-charging (Note 15)
F					Х	REF/SELF	ILLEGAL
	<u> </u>	L	L	Н	A Op-Code	MRS	ILLEGAL

Remark H = High level, L = Low level, X = High or Low level (Don't care)

4. Operative Command Table (Continued) (Note 7)

Current State	/CS	/R	/C	/W	Addr.	Command	Action
	Н	х	х	Х	х	DESL	Continue burst to end \rightarrow Pre-charging
	L	н	н	Н	х	NOP	Continue burst to end \rightarrow Pre-charging
	L	Н	Н	L	Х	BST	ILLEGAL
Read with	L	н	L	Н	BA/CA/A10	READ/READA	ILLEGAL ^(Note 9)
AP	L	Н	L	L	BA/CA/A10	WRIT/WRITA	ILLEGAL ^(Note 9)
	L	L	Н	Н	BA/RA	ACT	ILLEGAL ^(Note 9)
	L	L	Н	L	BA, A10	PRE/PALL	ILLEGAL ^(Note 9)
	L	L	L	Н	X	REF/SELF	ILLEGAL
	L	L	L	L	Op-Code	MRS	ILLEGAL
	н	х	х	Х	X	DESL	Burst to end \rightarrow Write recovering
							with auto pre-charge
	L	Н	Н	Н	Х	NOP	Continue burst to end \rightarrow Write recovering with auto pre-charge
	L	Н	Н	L	Х	BST	ILLEGAL
Write with	L	Н	L	Н	BA/CA/A10	READ/READA	ILLEGAL ^(Note 9)
AP	L	Н	L	L	BA/CA/A10	WRIT/WRITA	ILLEGAL ^(Note 9)
	L	L	Н	Н	BA/RA	ACT	ILLEGAL ^(Note 9)
	L	L	Н	L	BA, A10	PRE/PALL	ILLEGAL ^(Note 9)
	L	L	L	Н	Х	REF/SELF	ILLEGAL
	L	L	L	L	Op-Code	MRS	ILLEGAL
	Н	Х	Х	Х	Х	DESL	Nop \rightarrow Enter idle after t _{RP}
	L	Н	Н	Н	Х	NOP	Nop \rightarrow Enter idle after t _{RP}
	L	Н	Н	L	Х	BST	ILLEGAL
	L	Н	L	Н	BA/CA/A10	READ/READA	ILLEGAL (Note 9)
Pre-charging	L	Н	L	L	BA/CA/A10	WRIT/WRITA	ILLEGAL ^(Note 9)
	L	L	Н	Н	BA/RA	ACT	ILLEGAL ^(Note 9)
	L	L	Н	L	BA, A10	PRE/PALL	Nop \rightarrow Enter idle after t _{RP}
	L	L	L	Н	Х	REF/SELF	ILLEGAL
	L	L	L	L	Op-Code	MRS	ILLEGAL
	Н	Х	Х	Х	Х	DESL	Nop \rightarrow Enter idle after t _{RCD}
	L	Н	Н	Н	Х	NOP	Nop \rightarrow Enter idle after t _{RCD}
	L	Н	Н	L	Х	BST	ILLEGAL
Bow	L	Н	L	Н	BA/CA/A10	READ/READA	ILLEGAL (Note 9)
Row Activating	L	Н	L	L	BA/CA/A10	WRIT/WRITA	ILLEGAL (Note 9)
5	L	L	Н	Н	BA/RA	ACT	ILLEGAL (Note 9, 16)
	L	L	Н	L	BA, A10	PRE/PALL	ILLEGAL ^(Note 9)
	L	L	L	Н	Х	REF/SELF	ILLEGAL
	L	L	L	L	Op-Code	MRS	ILLEGAL

Remark H = High level, L = Low level, X = High or Low level (Don't care), AP = Auto Pre-charge

4. Operative Command Table (Continued) (Note 7)

Current State	/CS	/R	/C	/W	Addr.	Command	Action
	Н	Х	Х	Х	Х	DESL	Nop \rightarrow Enter row active after t _{DPL}
	L	Н	Н	Н	Х	NOP	Nop \rightarrow Enter row active after t _{DPL}
	L	Н	Н	L	Х	BST	Nop \rightarrow Enter row active after t _{DPL}
	L	Н	L	Н	BA/CA/A10	READ/READA	Start read, Determine AP
Write	L	н	L	L	BA/CA/A10	WRIT/WRITA	New write, Determine AP (Note 14)
Recovering	L	L	Н	Н	BA/RA	ACT	ILLEGAL ^(Note 9)
	L	L	Н	L	BA, A10	PRE/PALL	ILLEGAL ^(Note 9)
	L	L	L	Н	Х	REF/SELF	ILLEGAL
	L	L	L	L	Op-Code	MRS	ILLEGAL
	Н	Х	Х	Х	Х	DESL	Nop \rightarrow Enter pre-charge after t _{DPL}
	L	Н	Н	Н	Х	NOP	Nop \rightarrow Enter pre-charge after t _{DPL}
	L	Н	Н	L	Х	BST	Nop \rightarrow Enter pre-charge after t _{DPL}
Write	L	Н	L	Н	BA/CA/A10	READ/READA	ILLEGAL (Note 9, 14)
Recovering	L	Н	L	L	BA/CA/A10	WRIT/WRITA	ILLEGAL ^(Note 9)
with AP	L	L	Н	Н	BA/RA	ACT	ILLEGAL ^(Note 9)
	L	L	Н	L	BA, A10	PRE/PALL	ILLEGAL
	L	L	L	Н	Х	REF/SELF	ILLEGAL
	L	L	L	L	Op-Code	MRS	ILLEGAL
	Н	Х	Х	Х	Х	DESL	Nop \rightarrow Enter idle after t _{RC}
	L	Н	Н	Х	Х	NOP/BST	Nop \rightarrow Enter idle after t _{RC}
Refreshing	L	Н	L	Х	Х	READ/WRIT	ILLEGAL
	L	L	Н	Х	Х	ACT/PRE/PALL	ILLEGAL
	L	L	L	Х	Х	REF/SELF/MRS	ILLEGAL
	Н	Х	Х	Х	Х	DESL	Nop
Mode	L	Н	Н	Н	Х	NOP	Nop
Register	L	Н	Н	L	Х	BST	ILLEGAL
Accessing	L	Н	L	Х	Х	READ/WRIT	ILLEGAL
Ŭ	L	L	х	Х	Х	ACT/PRE/PALL/ REF/SELF/MRS	ILLEGAL

Remark H = High level, L = Low level, X = High or Low level (Don't care), AP = Auto Pre-charge

Note 7: All entries assume that CKE was active (High level) during the preceding clock cycle.

Note 8: If all banks are idle, and CKE is inactive (Low level), SDRAM will enter Power down mode. All input buffers except CKE will be disabled.

Note 9: Illegal to bank in specified states;

Function may be legal in the bank indicated by Bank Address (BA), depending on the state of that bank.

- *Note 10:* If all banks are idle, and CKE is inactive (Low level), SDRAM will enter Self refresh mode. All input buffers except CKE will be disabled.
- *Note 11:* Illegal if t_{RCD} is not satisfied.
- *Note 12:* Illegal if t_{RAS} is not satisfied.
- *Note 13:* Must satisfy burst interrupt condition.
- *Note 14:* Must satisfy bus contention, bus turn around, and/or write recovery requirements.
- *Note 15:* Must mask preceding data which don't satisfy t_{DPL}.

Note 16: Illegal if t_{RRD} is not satisfied.

5. Command Truth Table for CKE

$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Current State	Cł n-1	KE n	/CS	/R	/C	/W	Addr.	Action
Self RefreshLHLHHXXSelf refresh recoveryLHLHLXXILLEGALLHLXXXXILLEGALLLXXXXMaintain self refreshLHHXXXXILLEGALLLXXXXILLEGALHHLHXXILLEGALHHLLXXILLEGALHHLLXXILLEGALHLLHXXILLEGALHLLHXXILLEGALHLLHXXILLEGALHLLLXXILLEGALHLLLXXILLEGALHLLLXXILLEGALHLLLXXILLEGALHLLLXXILLEGALHLLLXXILLEGALHLLKXXILLEGALHLXXXXILLEGALHLLKXXILLEGALHLLKXXILLEGALHLLKXXX <td></td> <td></td> <td></td> <td>x</td> <td>х</td> <td>х</td> <td>х</td> <td>Х</td> <td></td>				x	х	х	х	Х	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $		L	Н	Н	Х	Х			
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Self Refresh	L		L		Н			
		L		L	Н				
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $		L	Н						
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $									
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $				Н					
Self Refresh RecoveryHHLLXXXXILLEGALHLLHHXXXILLEGALHLLLHXXILLEGALHLLLXXXILLEGALHLLLXXXILLEGALPower DownLHXXXXXLHXXXXXPower DownLHXXXXLHXXXXXPower DownLHXXXXHHHXXXXHHHXXXXHHLLHXXHHLLHXXHHLLHXXHHLLLHXHHLLLHXHHLLLHXHHLLLHXHHLLLHXHHLLLHXHHLLLHXHLLLHXXHLLLL				L		Н			
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $				L	Н				
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Self Refresh		Н						
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Recovery		L	Н					
HLLLXXXILLEGALPower DownLHXXXXXXINVALID, CLK(n-1) would exit power downLHXXXXXXExit power down \rightarrow IdleLLLXXXXMaintain power down \rightarrow IdleLHHXXXXMaintain power down \rightarrow IdleLHHHXXXMaintain power down \rightarrow IdleHHLHXXXMaintain power down \rightarrow IdleHHLLHXXMaintain power down \rightarrow IdleHHLLHXXMaintain power down \rightarrow IdleBoth BanksHHLLHXXIdleHHLLLDp-CodeRefer to operations in Operative Command TableHLLLLHXXXPower down (Note 17)HLLLLLLCop-CodeRefer to operations in Operative Command TableRow ActiveHXXXXXXPower down (Note 17)HHXXXXXXCommand TableAny State Other than Listed aboveHKXXXXXLHXXX <t< td=""><td></td><td></td><td>L</td><td>L</td><td>Н</td><td>Н</td><td></td><td></td><td></td></t<>			L	L	Н	Н			
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $			L	L	Н				ILLEGAL
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		Н	L	L	L	Х	Х	Х	ILLEGAL
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		н	х	х	х	х	х	Х	
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	Power Down	L	Н	Х	Х	Х	Х	Х	Exit power down \rightarrow Idle
HHHXXXXXRefer to operations in Operative Command TableHHLLLHXXCommand TableHHLLLLHXRefershHHLLLLOp-CodeRefer to operations in Operative Command TableHHLLLLOp-CodeRefer to operations in Operative Command TableHLLLHXXCommand TableHLLLHXXCommand TableHLLLLHXCommand TableHLLLLHXCommand TableRow ActiveHXXXXXPower down (Note 17)Row ActiveHXXXXXXAny State Other than Listed aboveHXXXXXLHXXXXXRefer to operations in Operative Command TableLHXXXXXXXCommand TableAny State Other than Listed aboveHLXXXXSegin clock suspend next cycleLHXXXXXXXXCommand TableLHXXXXXSegin clock suspend next cycle <td></td> <td>L</td> <td>L</td> <td>Х</td> <td>Х</td> <td>Х</td> <td>Х</td> <td>Х</td> <td>Maintain power down mode</td>		L	L	Х	Х	Х	Х	Х	Maintain power down mode
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		Н	Н	Н	Х				
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		Н	Н	L	Н				
$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$		Н	H	L	L	Н	Х		
Both Banks IdleHLHXXXXRefer to operations in Operative Command TableHLLLHXXCommand TableHLLLLHXSelf refresh (Note 17)HLLLLLOp-CodeRefer to operations in Operative Command TableHLXXXXXYHXXXXXYRow ActiveHXXXXXHXXXXXPower down (Note 17)Row ActiveHXXXXXHXXXXXPower down (Note 17)Any State Other than Listed aboveHLXXXXLHXXXXSelfer to operations in Operative Command TableLHHXXXXXAny State Other than Listed aboveHLXXXXLHXXXXXEstit clock suspend next cycleLHXXXXXXXLHXXXXXLHXXXXXLHXXXXXLHXXXXX<				L	L	L	Н		Refresh
Both Banks IdleHLLHXXCommand TableHLLLLHXCommand TableHLLLLHXSelf refresh (Note 17)HLLLLLHXLXXXXXPower down (Note 17)Refer to operations in Operative Command TableLXXXXRow ActiveHXXXXXLXXXXXPower down (Note 17)Row ActiveHXXXXXHHXXXXPower down (Note 17)HHXXXXXPower down (Note 17)Any State Other than Listed aboveHLXXXXXLHXXXXXEstit clock suspend next cycleLHXXXXXXXLHXXXXXLHXXXXXLHXXXXXLHXXXXXLHXXXXXLHXXXXXLHXXXXXLH <td< td=""><td></td><td></td><td>Н</td><td></td><td></td><td></td><td></td><td>Op-Code</td><td></td></td<>			Н					Op-Code	
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Both Banks			Н					
HLLLLHXSelf refresh (Note 17)HLLLLLLOp-CodeRefer to operations in Operative Command TableLXXXXXXPower down (Note 17)Row ActiveHXXXXXXLXXXXXRefer to operations in Operative Command TableRow ActiveHXXXXXHXXXXXPower down (Note 17)Row ActiveHXXXXXHHXXXXPower down (Note 17)Any State Other than Listed aboveHLXXXXLHXXXXXBegin clock suspend next cycle (Note 18)LHXXXXXXExit clock suspend next cycle									Command Table
HLLLLLQp-CodeRefer to operations in Operative Command TableLXXXXXXPower down (Note 17)Row ActiveHXXXXXXRefer to operations in Operative Command TableRow ActiveHXXXXXXLXXXXXXPower down (Note 17)LXXXXXXPower down (Note 17)HHXXXXXPower down (Note 17)Any State Other than Listed aboveHLXXXXLHXXXXXSegin clock suspend next cycle (Note 18)LHXXXXXXExit clock suspend next cycle						н			
HLLLLOp-CodeCommand TableLXXXXXPower down (Note 17)Row ActiveHXXXXXXLXXXXXXLXXXXXPower down (Note 17)Any State Other than Listed aboveHLXXXXLHXXXXSLHXXXXSLHXXXXXExit clock suspend next cycleLHXXXXLHXXXXLHXXXXLHXXXXLHXXXXLHXXXXLHXXXXLHXXXXLXXXXXLXXXXLXXXXLXXXXLXXXXLXXXXLXXXXLXXXXLXXXXLXXXXL <td< td=""><td></td><td>Н</td><td>L</td><td>L</td><td>L</td><td>L</td><td>н</td><td>Х</td><td>Self refresh (Note 17)</td></td<>		Н	L	L	L	L	н	Х	Self refresh (Note 17)
Row ActiveHXXXXXXXRefer to operations in Operative Command TableLXXXXXYPower down (Note 17)Any State Other than Listed aboveHHXXXXRefer to operations in Operative Command TableLHXXXXXBegin clock suspend next cycle (Note 18)LHXXXXXExit clock suspend next cycle		н	L	L	L	L	L	Op-Code	Command Table
Row ActiveHXXXXXXXRefer to operations in Operative Command TableLXXXXXYPower down (Note 17)Any State Other than Listed aboveHHXXXXRefer to operations in Operative Command TableLHXXXXXBegin clock suspend next cycle (Note 18)LHXXXXXExit clock suspend next cycle		L	Х	Х	Х	Х	Х	Х	Power down ^(Note 17)
LXXXXXXPower down (Note 17)Any State Other than Listed aboveHHXXXXXRefer to operations in Operative Command TableHLXXXXXSegin clock suspend next cycle (Note 18)LHXXXXXX	Row Active	н	Х	х	х	х	х	х	Refer to operations in Operative
Any State Other than Listed aboveHHXXXXXRefer to operations in Operative Command TableHLXXXXXBegin clock suspend next cycle (Note 18)LHXXXXXX		L	Х	Х	х	х	х	Х	(11242 47)
than Listed above H L X X X X (Note 18) L H X X X X Exit clock suspend next cycle									Refer to operations in Operative
		н	L	х	х	х	х	Х	
		L	н	Х	х	х	Х	Х	Exit clock suspend next cycle
		L	L	X	X	X	X	X	Maintain clock suspend

 L
 L
 X
 X
 X
 X
 Maintain clock suspend

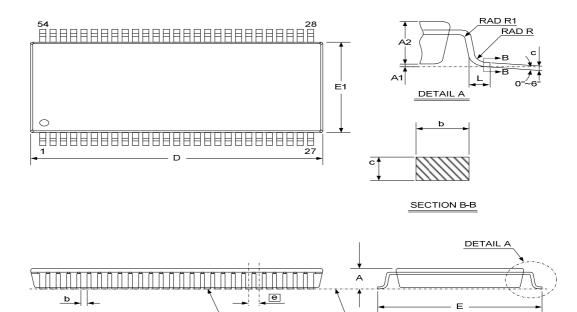
 Remark: H = High level, L = Low level, X = High or Low level (Don't care)

Notes 17: Self refresh can be entered only from the both banks idle state.

Power down can be entered only from both banks idle or row active state.

Notes 18: Must be legal command as defined in Operative Command Table

Package Description



0.100 (0.004'')

SEATING PLANE

DIM	Ν	AILLIMETER	6		INCHES			
DIIVI	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.		
A	_	_	1.20	-	_	0.047		
A1	0.05	-	0.15	0.002	_	0.006		
A2	0.95	1.00	1.05	0.037	0.039	0.041		
b	0.30	_	0.45	0.012	_	0.018		
С	0.12	-	0.21	0.005	_	0.008		
D	22.09	22.22	22.35	0.870	0.875	0.880		
е		0.80 BASIC		0.0315 BASIC				
E	11.56	11.76	11.96	0.455	0.463	0.471		
E1	10.03	10.16	10.29	0.395	0.400	0.405		
L	0.40	0.50	0.60	0.016	0.020	0.024		
R	0.12	_	0.25	0.005	_	0.010		
R1	0.12	_	_	0.005	_	-		

* Controlling dimension: millimeters

* Dimension D does not include mold protrusion. Mold protrusion shall not exceed 0.15mm (0.006") per side. Dimension E1 does not include interlead protrusion. Interlead protrusion shall not exceed 0.25mm (0.01") per side.

* Dimension b does not include dambar protrusions/intrusion. Allowable dambar protrusion shall not cause the lead to be wider than the MAX b dimension by more than 0.13mm. Dambar intrusion shall not cause the lead to be narrower than the MIN b dimension by more than 0.07mm.